

Dual Common-Cathode Ultra Low VF Schottky Rectifier

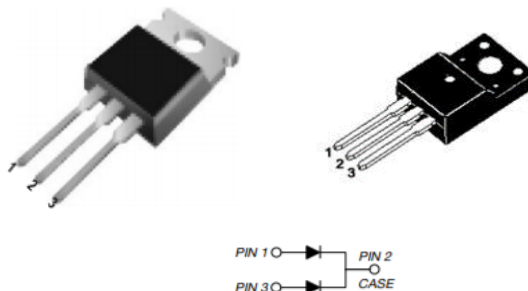
FEATURES AND BENEFITS

- Low power loss, high efficiency operation
- Low forward voltage drop
- Fast switching capability
- High forward surge capability
- Excellent High Temperature Stability

MECHANICAL DATA

- Epoxy : UL94 V-0 rated flame retardant
- Case: TO-220AB / ITO-220AB Package
- Terminals: Matte Tin annealed over copper
- Weight: Approximated 2.03 grams

Primary Characteristic	
I_O	2X5A
V_{RRM}	100V
I_{FSM}	100A
V_F Typical=1A, $T_J=125^\circ\text{C}$	0.37V
T_{Jmax}	175°C



Maximum Ratings (Ta=25°C unless otherwise specified)						
Characteristics			Symbol	Value		Unit
Peak Repetitive Reverse Voltage			V _{RRM}	100		V
Working Peak Reverse Voltage			V _{RWM}	100		V
DC Blocking Voltage			V _{DC}	100		V
RMS Reverse Voltage			V _{RMS}	70		V
Average Forward Rectified Current (per diode)			I _O	5		Amps
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)			I _{FSM}	100		Amps
Electrical Characteristics (Ta=25°C unless otherwise specified)						
Characteristics			Symbol	Typ.	Max.	Unit
Forward Voltage Drop ¹⁾	IF=1A	Ta=25°C	V _F	0.46	0.50	V
	IF=5A	Ta=25°C	V _F	0.69	0.73	V
	IF=1A	Ta=125°C	V _F	0.37	0.41	V
	IF=5A	Ta=125°C	V _F	0.60	0.64	V
Reverse Current ²⁾	VR=100V	Ta=25°C	I _R	10	30	µA
	VR=100V	Ta=125°C	I _R	3	9	mA

THERMAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)				
Characteristics		Symbol	Value	Unit
Typical Thermal Resistance, junction to case	TO-220AB	$R_{\theta JC}$	2.8	$^\circ\text{C/W}$
Typical Thermal Resistance, junction to case	ITO-220AB	$R_{\theta JC}$	4.0	$^\circ\text{C/W}$
Operating Temperature Range (in DC Mode)		T_J	-65 to +175	$^\circ\text{C}$
Storage Temperature Range		T_{STG}	-65 to +150	$^\circ\text{C}$

Notes (1): Pulse test: 300 μs pulse width, 1% duty cycle.

Notes (2): Pulse width $\leq 40\text{ms}$

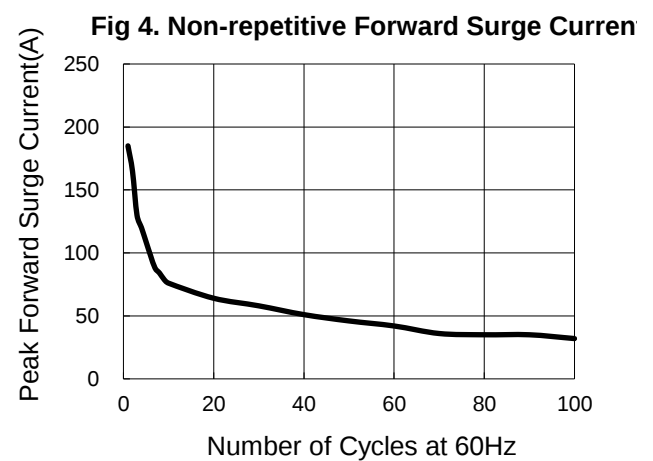
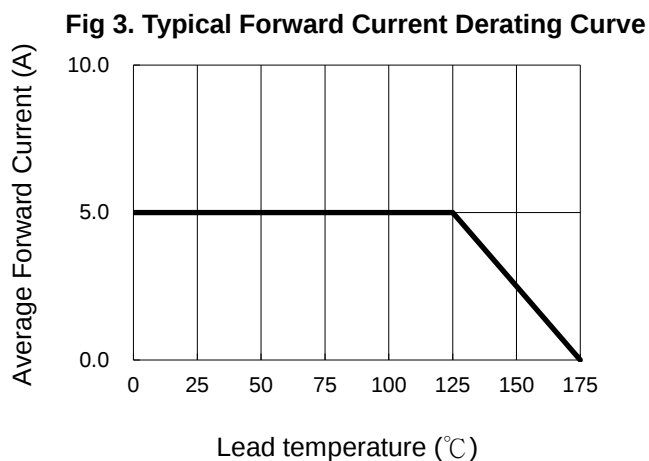
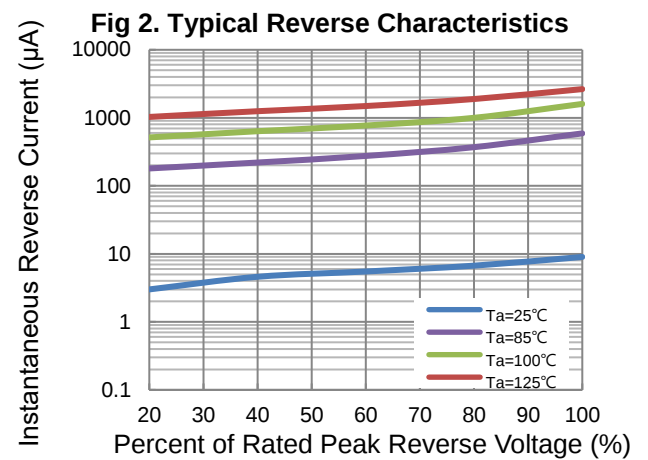
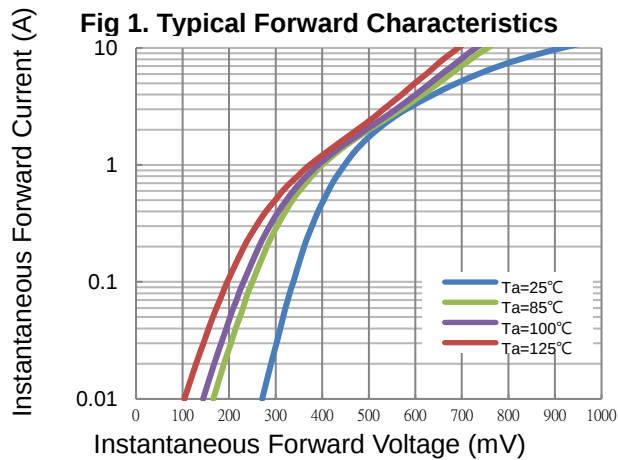
Notes (3): FR-4 PCB, 2oz copper. Minimum recommended pad layout

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Revision:V1.11

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RATINGS AND CHARACTERISTICS CURVES



Marking Information

**mO-SEMI
SLT10L100CT
AAABBBC**

**mO-SEMI
SLT10L100FCT
AAABBBC**

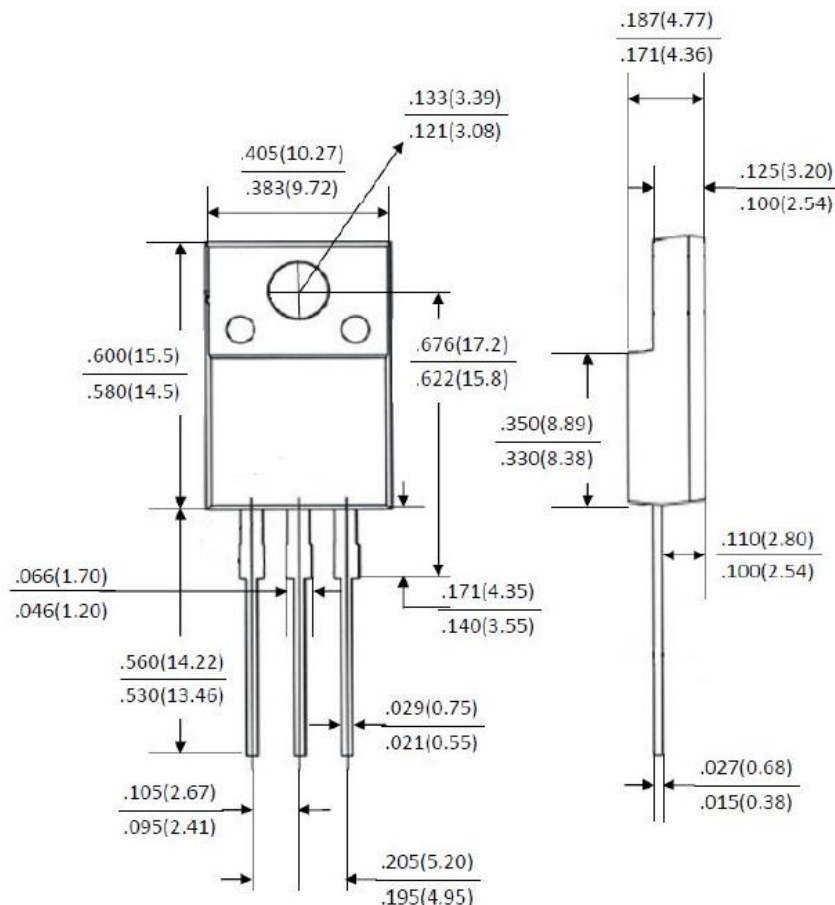
mO-SEMI =Series Name
 SLT10L100 =Part Number Marking Code
 AAABBBC =Product Tracking Code
 *FCT=ITO-220 =Dual ITO-220
 *CT=TO-220 =Dual TO-220

Package Outline Dimensions (in millimeters)

ITO-220 (Type 1)

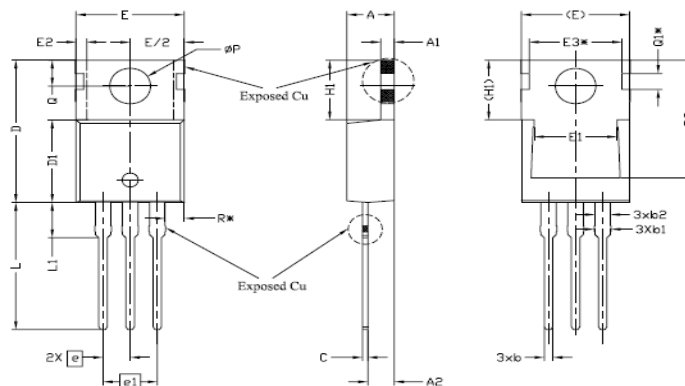
ITO-220				
SYMBOL	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A	4.60	4.80	0.18	0.19
b	0.70	0.91	0.03	0.04
b1	1.20	1.47	0.05	0.06
b2	1.10	1.30	0.04	0.05
C	0.45	0.63	0.02	0.02
D	15.80	15.97	0.62	0.63
e	2.40	2.70	0.09	0.11
E	10.00	10.30	0.39	0.41
F	2.44	2.64	0.10	0.10
G	6.50	6.90	0.26	0.27
L	12.90	13.30	0.51	0.52
L1	3.13	3.33	0.12	0.13
Q	2.65	2.85	0.10	0.11
Q1	3.20	3.40	0.13	0.13
ΦR	3.08	3.28	0.12	0.13

ITO-220 (Type 2)



TO-220 (Type 1)

TO-220				
SYMBOL	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A	4.24	4.64	0.17	0.18
A1	1.15	1.40	0.05	0.06
A2	2.30	2.70	0.09	0.11
b	0.70	0.90	0.03	0.04
b1	1.20	1.75	0.05	0.07
b2	1.20	1.70	0.05	0.07
c	0.40	0.60	0.02	0.02
D	14.70	16.00	0.58	0.63
D1	8.82	9.02	0.35	0.36
D2	12.43	12.83	0.49	0.51
E	9.96	10.36	0.39	0.41
E1	6.86	8.89	0.27	0.35
E2	-	0.76	-	0.03
E3*	8.7REF.			
e	2.54BSC			
e1	5.08BSC			
H1	6.30	6.60	0.25	0.26
L	13.47	13.97	0.53	0.55
L1	3.60	4.00	0.14	0.16
ΦP	3.75	3.93	0.15	0.15
Q	2.60	3.00	0.10	0.12
Q1*	1.73REF.			
R*	1.82REF.			



TO-220 (Type 2)

TO-220				
SYMBOL	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A	3.56	4.82	0.14	0.19
A1	0.51	1.39	0.02	0.05
A2	2.04	2.92	0.08	0.11
b	0.39	1.01	0.02	0.04
b1	1.15	1.82	0.05	0.07
b2	1.15	1.77	0.05	0.07
c	0.04	0.50	0.00	0.02
D	14.22	16.51	0.56	0.65
D1	8.39	9.01	0.33	0.35
D2	11.45	12.87	0.45	0.51
E	9.66	10.66	0.38	0.42
E1	6.86	8.89	0.27	0.35
e	2.54BSC		2.54BSC	
e1	5.08BSC		5.08BSC	
H1	5.85	6.85	0.23	0.27
L	12.70	14.73	0.50	0.58
L1	-	6.35	-	0.25
L2	15.80	16.20	0.62	0.64
ΦP	3.54	4.08	0.14	0.16
Q	2.54	3.42	0.10	0.13

